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APPLICATION NO.
10/536,696

APPLICANT
Arnaud GRISARD et al.

FILING DATE
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GROUP

U.S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						Yes	No

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

J.R./	Christopher B. Ebert, Loren A. Eyres, Martin M. Fejer, James S. Harris, Jr. "MBE growth of antiphase GaAs films using GaAs/Ge/GaAs heteroepitaxy" Journal of Crystal Growth 201/202 (1888) 187-193	
EXAMINER	/Joshel Rivera/	DATE CONSIDERED 11/18/2009

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.